

# MBR1035CT - MBR10200CT

10.0 AMPS. Schottky Barrier Rectifiers



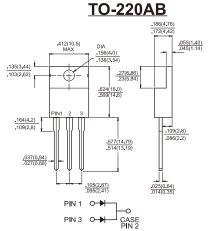


### **Features**

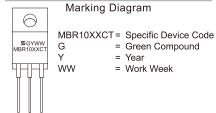
- UL Recognized File # E-326243
- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
  For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection
- High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case
- Green compound with suffix "G" on packing code & prefix "G" on datecode.

## **Mechanical Data**

- Cases: JEDEC TO-220AB molded plastic body Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- Polarity: As marked
- Mounting position: Any
- Mounting torque: 5 in. lbs. max Weight: 1.88grams



Dimensions in inches and (millimeters)



## Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

Type Number	Symbol	MBR 1035 CT	MBR 1045 CT	MBR 1050 CT	MBR 1060 CT	MBR 1090 CT	MBR 10100 CT	MBR 10150 CT	MBR 10200 CT	Units
Maximum Recurrent Peak Reverse Voltage	Vrrm	35	45	50	60	90	100	150	200	V
Maximum RMS Voltage	VRMS	24	31	35	42	63	70	105	140	V
Maximum DC Blocking Voltage	VDC	35	45	50	60	90	100	150	200	V
Maximum Average Forward Rectified Current at Tc=125°C	<b>I</b> F(AV)	10							А	
Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20KHz) at Tc=125°C	IFRM	10							А	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	IFSM	120							А	
Peak Repetitive Reverse Surge Current (Note 2)	IRRM	1.0 0.5						Α		
Maximum Instantaneous Forward Voltage at: $I_r$ =5A, $T_A$ =25°C $I_r$ =5A, $T_A$ =125°C $I_r$ =10A, $T_A$ =25°C $I_r$ =10A, $T_A$ =125°C	VF	0. 0.	70 57 80 67	0. 0.	80 65 90 75	0. 0.	85 75 95 85	0. 0.		V
Maximum Instantaneous Reverse Current @ TA =25 °C at Rated DC Blocking Voltage (Note 1) @ TA=125 °C		0.1								mA
	l R	1	5	1	0	2	.0	5	.0	mA
Voltage Rate of Change (Rated V <sub>R</sub> )	dV/dt	10,000							V/uS	
Maximum ⊺ypical ⊤hermal Resistance (Note 3)	Rejc	1.5							°C/W	
Operating Junction Temperature Range	TJ	-65 to +150						°C		
Storage Temperature Range	Тѕтс	-65 to +175							°C	

Notes: 1. Pulse Test: 300us Pulse Width, 1% Duty Cycle

- 2. 2.0us Pulse Width, f=1.0 KHz 3. Mount on Heatsink Size of 2 in x 3 in x 0.25in Al-Plate.

Version: G10



#### RATINGS AND CHARACTERISTIC CURVES (MBR1035CT THRU MBR10200CT)

